

## Epitaxial thick films by spray pyrolysis for coated conductors

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### Abstract

Spray pyrolysis has been successfully used to synthesize many oxides, like transparent conducting films ( $\text{SnO}_2$ ,  $\text{ZnO}$  and  $\text{InO}_3$ ) or cuprate-based superconducting films. The technique has a high deposition rate and uses cheap raw materials in non-vacuum environment. In our work spray pyrolysis has been used to grow superconducting epitaxial thick films of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$  (YBCO) on textured substrates. A precursor nitrate solution is atomized and carried towards a substrate which is heated between  $800^\circ\text{C}$  and  $900^\circ\text{C}$ . After growth, oxygenation is carried out by cooling under oxygen flow. YBCO films deposited on a single-crystal ( $\text{SrTiO}_3$ ) exhibit a very good c-axis orientation ( $\Delta\omega=0.4^\circ$ ) as well as an in-plane texture ( $\Delta\phi=0.6^\circ$ ). Transport measurement has given  $I_c$  value close to 10A (77K, sf) on a 5 mm wide tape. First YBCO depositions on technical substrates made by ion beam assisted deposition (IBAD) display a quite good out-of-plane texture ( $\Delta\omega=7^\circ$ ) and a  $T_{c_{\text{onset}}}$  of 90K. Furthermore, prospective work on buffer layers ( $\text{Y}_2\text{O}_3$ ,  $\text{CeO}_2$ ,  $\text{CuO}$ ) synthesis has been carried out. Despite the high potential of spray pyrolysis, the mechanisms involved in the deposition are quite unknown. It has been evidenced a narrow relationship between the precursor decomposition and the properties of the deposition. In particular an important difference

between the decomposition temperatures of the precursors implies a modification of the stoichiometry in the film. In certain cases  $\text{NO}_2$  outgassing can be problematic as it can induce cracks or foam morphology.